

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT428 (DPAK) surface mountable plastic package intended for use in applications requiring sensitive gate, high bidirectional blocking voltage capability, high surge current capability and high thermal cycling performance.

2. Features and benefits

- High bidirectional blocking voltage capability
- High surge current capability
- High thermal cycling performance
- Sensitive gate
- Surface mountable package

3. Applications

- Ignition circuits
- Motor control
- Protection circuits
- Voltage regulation

4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Cymbol	i arameter	Conditions			чур	Max	Unit
V _{RRM}	repetitive peak reverse voltage			-	-	650	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 103 °C; <u>Fig. 1</u>		-	-	7.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; $T_{mb} \le 103 \text{ °C}$; Fig. 2; Fig. 3		-	-	12	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>		-	-	120	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms		-	-	132	A
Tj	junction temperature			-	-	125	°C
Static chara	acteristics						
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>		-	2	15	mA
Dynamic ch	narateristics	· · · · · · · · · · · · · · · · · · ·	· · ·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 436 V; T _j = 125 °C; R _{GK} = 100 Ω; exponential waveform; Fig. 13		200	1000	-	V/µs

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V_{DM} = 436 V; T _j = 125 °C; exponential waveform; gate open circuit; Fig. 13	50	130	-	V/µs

5. Pinning information

Table 2. F	Pinning inf	ormation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	[]	А -Ң -К
2	А	anode		G sym037
3	G	gate		cymoor
mb	A	mounting base; connected to anode	DPAK (SOT428)	

6. Ordering information

Table 3. Ordering infor	mation		
Type number	Package		
	Name	Description	Version
BT151S-650R	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428

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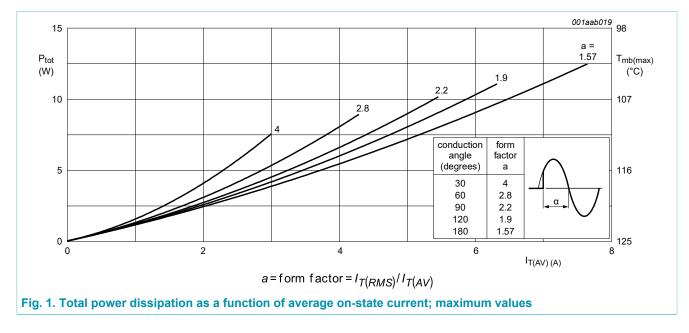
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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

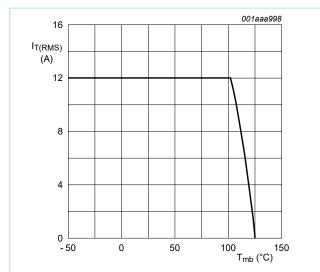
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	650	V
V _{RRM}	repetitive peak reverse voltage		-	650	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 103 °C; <u>Fig. 1</u>	-	7.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 103 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	12	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	-	120	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	132	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	72	A²s
dl _T /dt	rate of rise of on-state current	I _G = 30 mA	-	30	A/µs
I _{GM}	peak gate current		-	2	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



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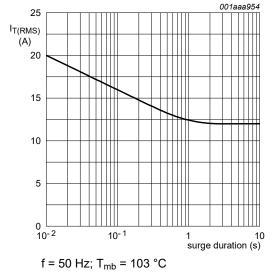
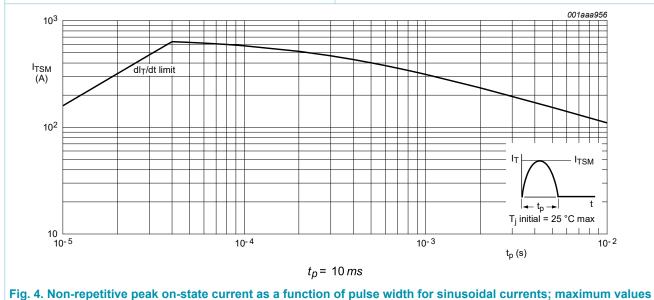


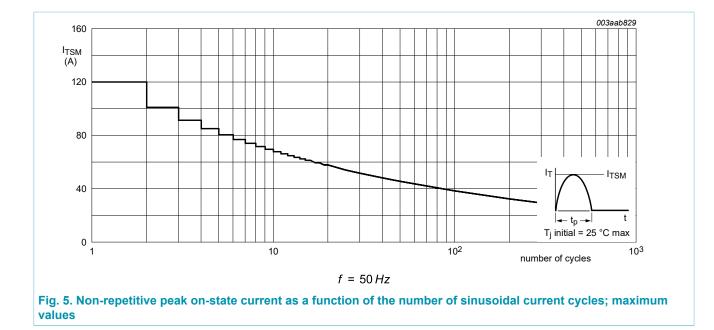
Fig. 2. RMS on-state current as a function of mounting base temperature; maximum values





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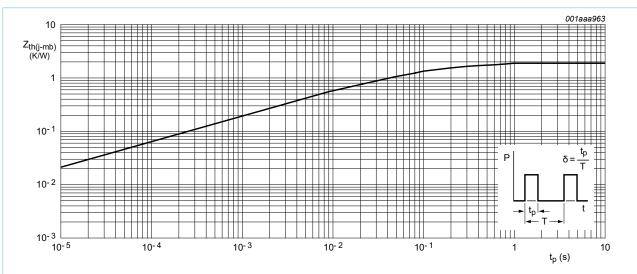


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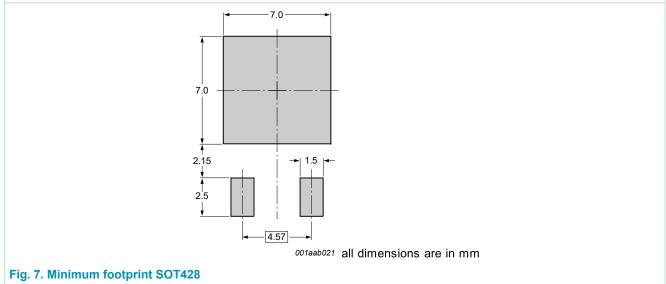
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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	1.8	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	mounted on an FR4 printed-circuit board; Fig. 7	-	75	-	K/W







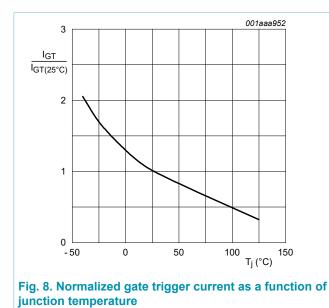
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9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · · · · · · · · · · · · · · · · ·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	-	2	15	mA
۱ _L	latching current	V _D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 9</u>	-	10	40	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	7	20	mA
V _T	on-state voltage	I _T = 23 A; T _j = 25 °C; <u>Fig. 11</u>	-	1.4	1.75	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 12	-	0.6	1.5	V
		V _D = 650 V; I _T = 0.1 A; T _j = 125 °C; Fig. 12	0.25	0.4	-	V
ID	off-state current	V _D = 650 V; T _j = 125 °C	-	0.1	0.5	mA
I _R	reverse current	V _R = 650 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic ch	narateristics		·	·		
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 436 V; T _j = 125 °C; R _{GK} = 100 Ω; exponential waveform; Fig. 13	200	1000	-	V/µs
		V_{DM} = 436 V; T _j = 125 °C; exponential waveform; gate open circuit; Fig. 13	50	130	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 40 A; V _D = 650 V; I _G = 0.1 A; dI _G / dt = 5 A/µs; T _j = 25 °C	-	2	-	μs
t _q	commutated turn-off time		-	70	-	μs



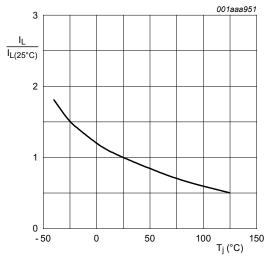
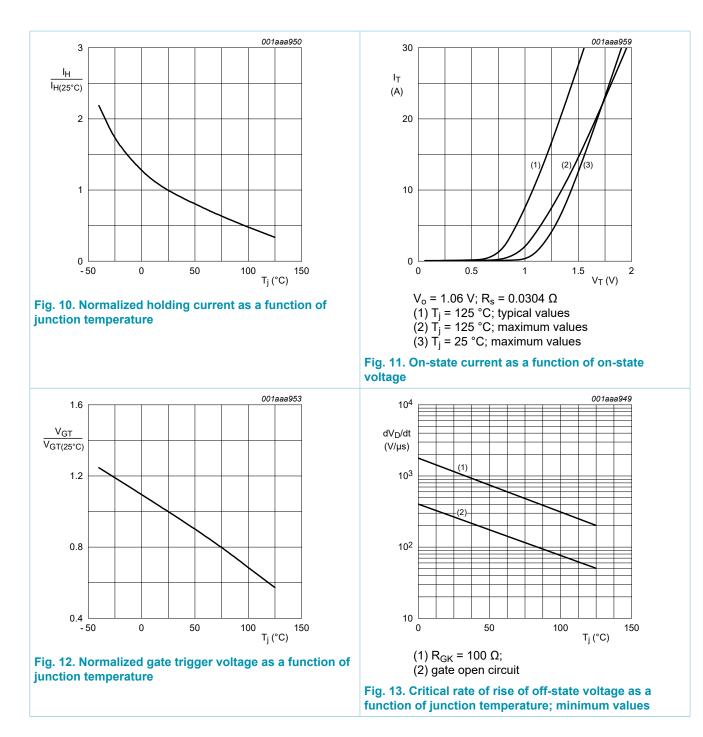


Fig. 9. Normalized latching current as a function of junction temperature

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10. Package outline

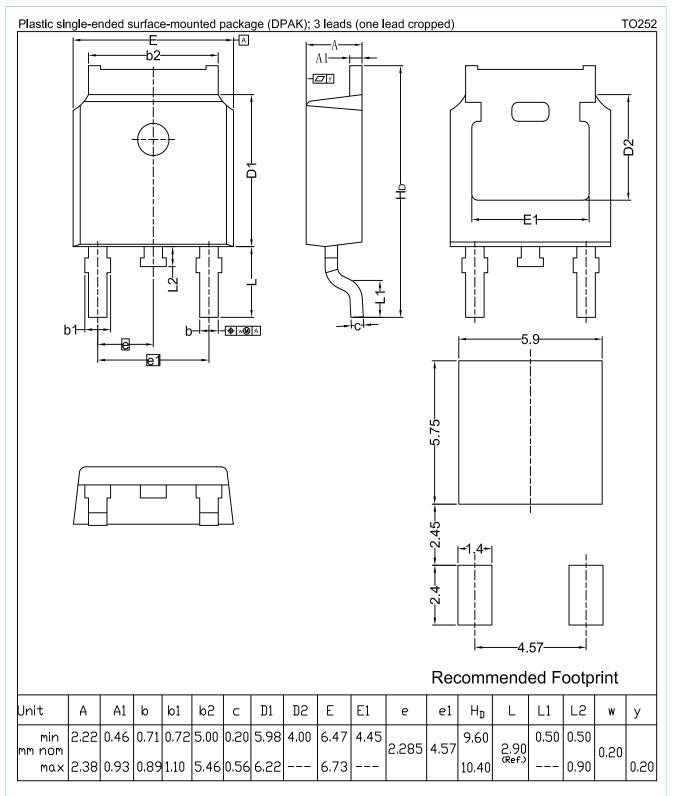


Fig. 14. Package outline DPAK (SOT428)

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11. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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